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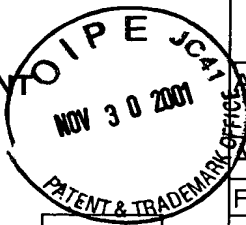
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Client Ref.

282780

57170-US-SuS/nh

**INFORMATION DISCLOSURE STATEMENT
BY APPLICANT**



Applicant: ASADA

Appln. No.: 09/922,918

Filing Date: August 7, 2001

Date: November 30, 2001

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of

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Examiner:

Group Art Unit: 2838

U.S. PATENT DOCUMENTS

Examiner's Initials*	Document Number	Date MM/YYYY	Name (Family Name of First Inventor)	Class	Sub Class	Filing Date (if appropriate)
JJ	AR 5,936,440	08/1999	ASADA et al.	327	110	
	BR					
	CR					
	DR					
	ER					
	FR					
	GR					
	HR					
	IR					
	JR					
	KR					
	LR					
	MR					
	NR					

FOREIGN PATENT DOCUMENTS

	Document Number	Date MM/YYYY	Country	Inventor Name	English Abstract		Translation Readily Available	
					Enclosed	No	Enclose	No
JJ	OR WO 00/27032	05/2000	GERMANY	MAGRUDER et al	x		x	
JJ	PR DE 19755653	07/1998	GERMANY	NAOYUKI et al	x			x
JJ	QR 06022470	01/1994	JAPAN	YUJI	x			x
JJ	RR 0 678983 A1	10/1995	EUROPE	PENZA	x		x	
JJ	SR GB 2318467	04/1998	UK	CLEMENTE	x		x	
	TR							
	UR							
	VR							
	WR							
	XR							

OTHER (Including in this order Author, Title, Periodical Name, Date, Pertinent Pages, etc.)

JJ	YR	H.P. Yee, Ph.D., "An EMI Suppression MOSFET Driver, IEEE, 1997, pp. 242-248			
	ZR				
	AAR				
	BBR				
	CCR				
	DDR				

Examiner

Julio Gonzalez

Date Considered:

03/18/03

*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.